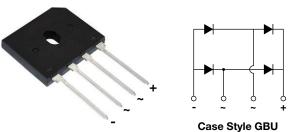
GBU25H08



Vishay General Semiconductor

Single In-Line Bridge Rectifier



Case Style GBU

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	25 A				
V _{RRM}	800 V				
I _{FSM}	350 A				
V _F at I _F = 12.5 A (125 °C)	0.86 V				
T _J max.	175 °C				
Package	GBU				
Circuit configuration	In-line				

FEATURES

- UL recognition file number E312394
- Glass passivated pellet chip junction
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Ideal for printed circuit boards
- High surge current capability
- High case dielectric strength of 2000 V_{RMS}, 1 minute
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

General purpose use in AC/DC bridge full wave rectification for switching power supply, home applications, and white-goods applications specially or telecom power supply, game PC

MECHANICAL DATA

Case: GBU

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and industrial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD22-B102

M3 suffix meet JESD 201 class 1A whisker test

Polarity: as marked on body

Mounting Torque: 10 cm-kg (8.8 inches-lbs) max.

Recommended Torque: 5.7 cm-kg (5 inches-lbs)

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	GBU25H08	UNIT	
Device marking code		GBU25H08			
Maximum repetitive peak reverse voltage	V _{RRM}	800	V		
Maximum RMS voltage	V _{RMS}	560	V		
Maximum DC blocking voltage		V _{DC}	800	V	
Maximum average forward rectified output current at	T _C = 120 °C	I _O ⁽¹⁾	25	- A	
	T _A = 25 °C	I _O ⁽²⁾	4.5		
Non-repetitive peak forward surge current 8.3 ms single sine-wave, $T_J = 25 \ ^{\circ}C$		I _{FSM}	350	А	
Non-repetitive peak forward surge current 1.0 ms single sine-wave, $T_J = 25 ^{\circ}\text{C}$		I _{FSM}	700	А	
Rating for fusing (t < 8.3 ms)		l ² t	508	A ² s	
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +175	°C	

Notes

⁽¹⁾ Unit case mounted on aluminum plate heatsink

(2) Units mounted on PCB without heatsink

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COMPLIANT

HALOGEN

FREE

GBU25H08



www.vishay.com

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ELECTRICAL CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Maximum instantaneous forward voltage drop	I _F = 12.5 A	T _J = 25 °C	V _F ⁽¹⁾	0.97	1.05	V	
per diode	$I_{\rm F} = 12.3$ A	T _J = 125 °C	VF \	0.86	-	v	
Maximum DC reverse current at rated DC	V _B = 800 V	T _J = 25 °C	I _R ⁽²⁾	-	10		
blocking voltage per diode	v _R = 000 v	T _J = 125 °C	'R (=/	45	-	μA	
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t _{rr}	3500	-	ns	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	100	-	pF	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL GBU25H08		UNIT		
Typical thermal resistance	R _{0JA} ⁽¹⁾	24	°C/W		
Typical memaresistance	R _{0JC} ⁽²⁾	4			

Notes

⁽¹⁾ Without heatsink, free air

(2) With heatsink

ORDERING INFORMATION							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
GBU25H08-M3/P	3.87	Р	20	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

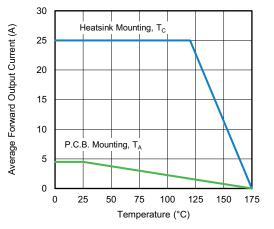


Fig. 1 - Derating Curve Output Rectified Current

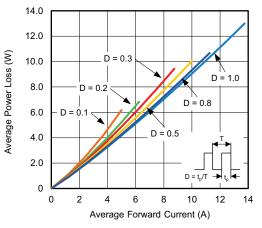


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current . Per Diode





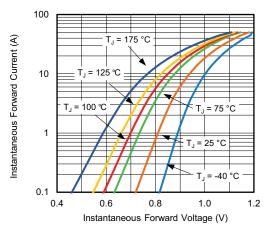


Fig. 3 - Typical Forward Characteristics Per Diode

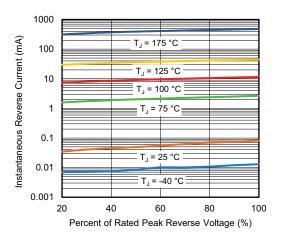


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

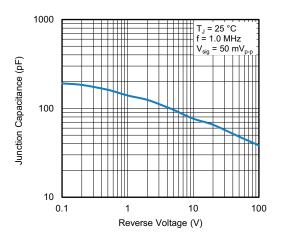


Fig. 5 - Typical Junction Capacitance Per Diode

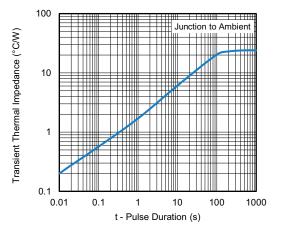


Fig. 6 - Typical Transient Thermal Impedance Per Diode

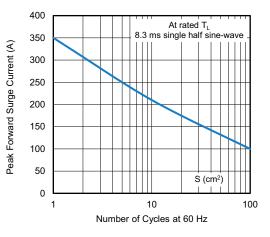


Fig. 7 - Peak Forward Surge Current

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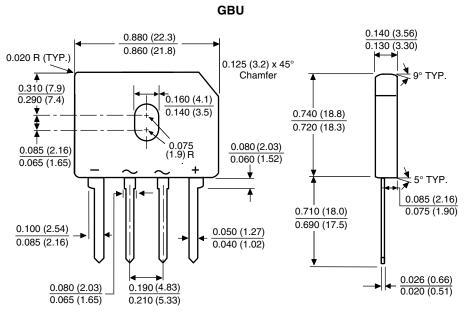
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Polarity shown on front side of case, positive lead by beveled corner



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Revision: 01-Jan-2024